

Surface Mount Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical applications are in switching Mode Power Supplies such as adaptors, DC/DC converters free-wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * High Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-0
- * Pb free
- * In compliance with EU RoHs directives

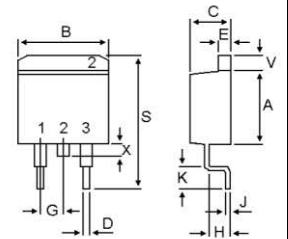


SCHOTTKY BARRIER RECTIFIERS

**20 AMPERES
100 VOLTS**



TO-263



DIM	MILLIMETERS	
	MIN	MAX
A	8.30	9.20
B	9.80	10.40
C	4.30	4.80
D	0.65	0.95
E	1.17	1.43
G	2.39	2.69
H	2.68	3.32
J	0.35	0.65
K	2.29	2.90
S	14.60	15.88
V	1.10	1.50
X	---	2.00

MAXIMUM RATINGS

Characteristic	Symbol	MBRS20100CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R)	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I_{FSM}	150	A
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +175	°C

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta jc}$	5.4	°C/w
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ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage (per diode) ($I_F = 10$ Amp $T_C = 25^\circ C$) ($I_F = 10$ Amp $T_C = 125^\circ C$)	V_F	---	0.80 0.65	0.85 ---	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ C$) (Rated DC Voltage, $T_C = 125^\circ C$)	I_R	---	2 5	10 ---	μA mA

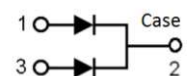


FIG-1 FORWARD CURRENT DERATING CURVE

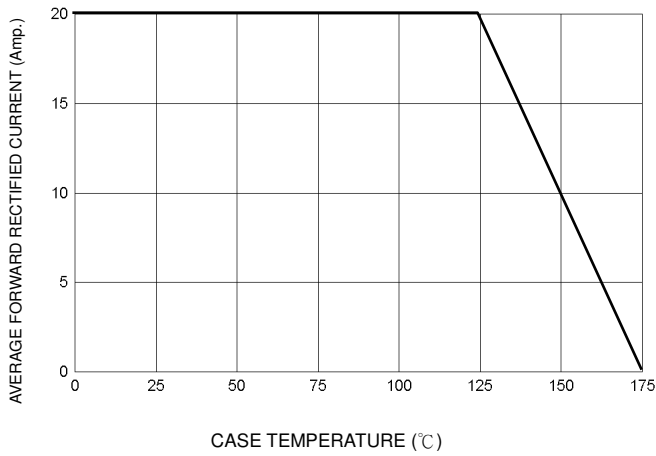


FIG-2 TYPICAL FORWARD CHARACTERISTICS

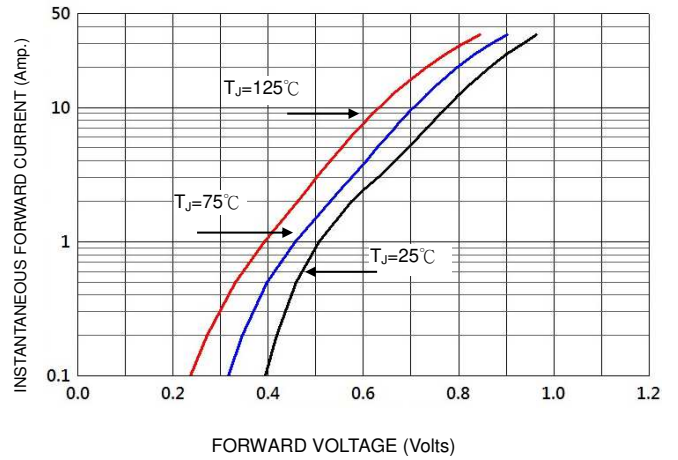


FIG-3 TYPICAL REVERSE CHARACTERISTICS

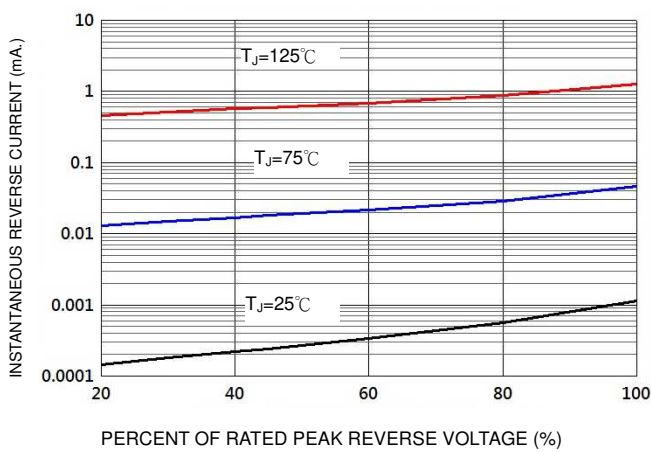


FIG-4 TYPICAL JUNCTION CAPACITANCE

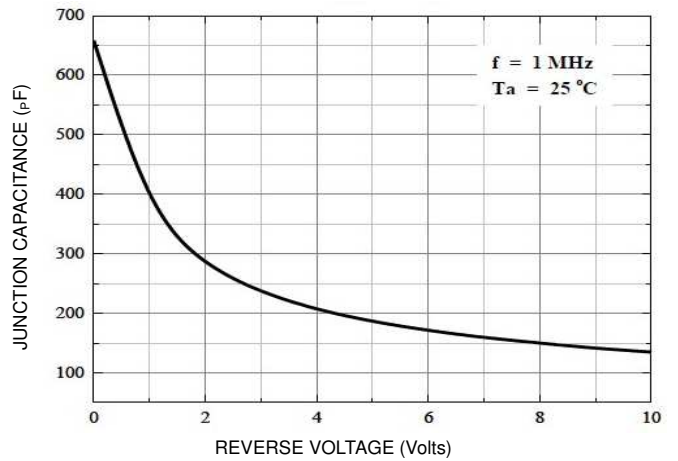
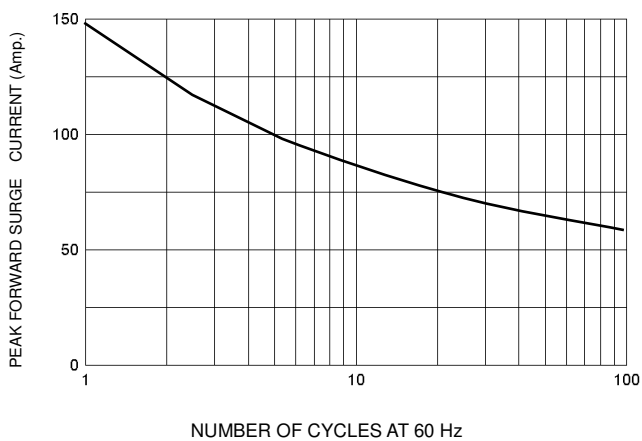


FIG-5 PEAK FORWARD SURGE CURRENT



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